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# FQPF9N25C / FQPF9N25CT

## N-Channel QFET® MOSFET

250 V, 8.8 A, 430 mΩ

### Features

- 8.8 A, 250 V,  $R_{DS(on)} = 430 \text{ m}\Omega$  (Max.) @  $V_{GS} = 10 \text{ V}$ ,  $I_D = 4.4 \text{ A}$
- Low Gate Charge (Typ. 26.5 nC)
- Low  $C_{rss}$  (Typ. 45.5 pF)
- 100% Avalanche Tested

### Description

These N-Channel enhancement mode power field effect transistors are produced using Fairchild's proprietary, planar stripe, DMOS technology.

This advanced technology has been especially tailored to minimize on-state resistance, provide superior switching performance, and withstand high energy pulse in the avalanche and commutation mode. These devices are well suited for high efficiency switching DC/DC converters, switch mode power supplies, DC-AC converters for uninterrupted power supplies and motor controls.



### MOSFET Maximum Ratings $T_C = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	FQPF9N25C / FQPF9N25CT	Unit
$V_{DSS}$	Drain to Source Voltage	250	V
$I_D$	Drain Current	- Continuous ( $T_C = 25^\circ\text{C}$ )	8.8 *
		- Continuous ( $T_C = 100^\circ\text{C}$ )	5.6 *
$I_{DM}$	Drain Current	- Pulsed (Note 1)	35.2 *
$V_{GSS}$	Gate to Source Voltage	$\pm 30$	V
$E_{AS}$	Single Pulsed Avalanche Energy	(Note 2)	285
$I_{AR}$	Avalanche Current	(Note 1)	8.8
$E_{AR}$	Repetitive Avalanche Energy	(Note 1)	7.4
dv/dt	Peak Diode Recovery dv/dt	(Note 3)	5.5
$P_D$	Power Dissipation	( $T_C = 25^\circ\text{C}$ )	38
		- Derate Above $25^\circ\text{C}$	0.3
$T_J, T_{STG}$	Operating and Storage Temperature Range	-55 to +150	$^\circ\text{C}$
$T_L$	Maximum Lead Temperature for Soldering Purpose, 1/8" from Case for 5 Seconds	300	$^\circ\text{C}$

\*Drain current limited by maximum junction temperature

### Thermal Characteristics

Symbol	Parameter	FQPF9N25C / FQPF9N25CT	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.	3.29	$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient, Max.	62.5	

## Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FQPF9N25C	FQPF9N25C	TO-220F	Tube	N/A	50 units
FQPF9N25CT	FQPF9N25CT	TO-220F	Tube	N/A	50 units

## Electrical Characteristics $T_C = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
<b>Off Characteristics</b>						
$BV_{DSS}$	Drain-Source Breakdown Voltage	$V_{GS} = 0\text{ V}, I_D = 250\ \mu\text{A}$	250	--	--	V
$\Delta BV_{DSS} / \Delta T_J$	Breakdown Voltage Temperature Coefficient	$I_D = 250\ \mu\text{A}$ , Referenced to $25^\circ\text{C}$	--	0.30	--	$\text{V}/^\circ\text{C}$
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{DS} = 250\text{ V}, V_{GS} = 0\text{ V}$ $V_{DS} = 200\text{ V}, T_C = 125^\circ\text{C}$	--	--	10 100	$\mu\text{A}$ $\mu\text{A}$
$I_{GSSF}$	Gate-Body Leakage Current, Forward	$V_{GS} = 30\text{ V}, V_{DS} = 0\text{ V}$	--	--	100	nA
$I_{GSSR}$	Gate-Body Leakage Current, Reverse	$V_{GS} = -30\text{ V}, V_{DS} = 0\text{ V}$	--	--	-100	nA
<b>On Characteristics</b>						
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250\ \mu\text{A}$	2.0	--	4.0	V
$R_{DS(on)}$	Static Drain-Source On-Resistance	$V_{GS} = 10\text{ V}, I_D = 4.4\text{ A}$	--	0.35	0.43	$\Omega$
$g_{FS}$	Forward Transconductance	$V_{DS} = 40\text{ V}, I_D = 4.4\text{ A}$	--	7.0	--	S
<b>Dynamic Characteristics</b>						
$C_{iss}$	Input Capacitance	$V_{DS} = 25\text{ V}, V_{GS} = 0\text{ V}$	--	545	710	pF
$C_{oss}$	Output Capacitance	$f = 1.0\text{ MHz}$	--	115	150	pF
$C_{riss}$	Reverse Transfer Capacitance		--	45.5	60	pF
<b>Switching Characteristics</b>						
$t_{d(on)}$	Turn-On Delay Time	$V_{DD} = 125\text{ V}, I_D = 8.8\text{ A}$ , $V_{GS} = 10\text{ V}, R_G = 25\ \Omega$	--	15	40	ns
$t_r$	Turn-On Rise Time		--	85	180	ns
$t_{d(off)}$	Turn-Off Delay Time		--	90	190	ns
$t_f$	Turn-Off Fall Time		(Note 4)	--	65	140
$Q_g$	Total Gate Charge	$V_{DS} = 200\text{ V}, I_D = 8.8\text{ A}$ , $V_{GS} = 10\text{ V}$	--	26.5	35	nC
$Q_{gs}$	Gate-Source Charge		--	3.5	--	nC
$Q_{gd}$	Gate-Drain Charge		(Note 4)	--	13.5	--
<b>Drain-Source Diode Characteristics and Maximum Ratings</b>						
$I_S$	Maximum Continuous Drain-Source Diode Forward Current		--	--	8.8	A
$I_{SM}$	Maximum Pulsed Drain-Source Diode Forward Current		--	--	35.2	A
$V_{SD}$	Drain-Source Diode Forward Voltage	$V_{GS} = 0\text{ V}, I_S = 8.8\text{ A}$	--	--	1.5	V
$t_{rr}$	Reverse Recovery Time	$V_{GS} = 0\text{ V}, I_S = 8.8\text{ A}$ , $di_F / dt = 100\text{ A}/\mu\text{s}$	--	218	--	ns
$Q_{rr}$	Reverse Recovery Charge		--	1.58	--	$\mu\text{C}$

**Notes:**

1. Repetitive rating : pulse-width limited by maximum junction temperature.
2.  $L = 5.9\text{ mH}, I_{AS} = 8.8\text{ A}, V_{DD} = 50\text{ V}, R_G = 25\ \Omega$ , starting  $T_J = 25^\circ\text{C}$ .
3.  $I_{SD} \leq 8.8\text{ A}, di/dt \leq 300\text{ A}/\mu\text{s}, V_{DD} \leq BV_{DSS}$ , starting  $T_J = 25^\circ\text{C}$ .
4. Essentially independent of operating temperature.

## Typical Characteristics

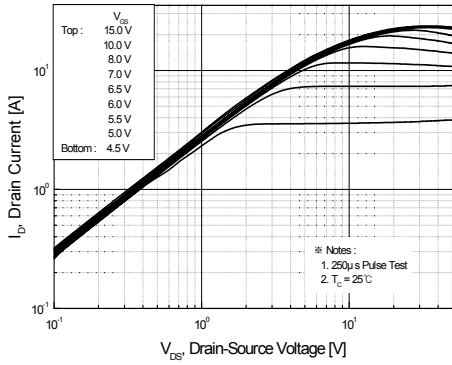


Figure 1. On-Region Characteristics

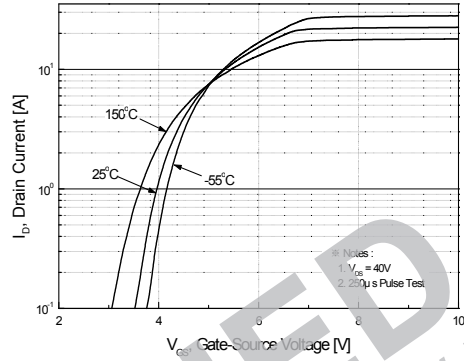


Figure 2. Transfer Characteristics

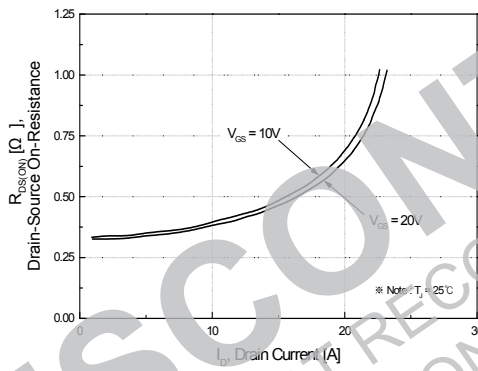


Figure 3. On-Resistance Variation vs Drain Current and Gate Voltage

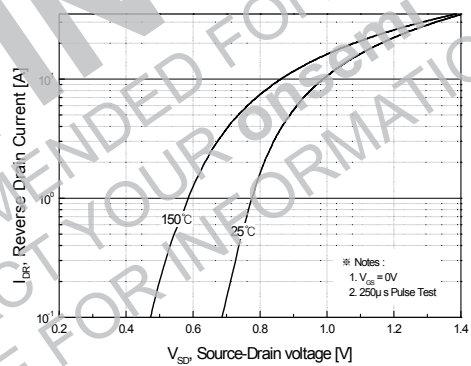


Figure 4. Body Diode Forward Voltage Variation with Source Current and Temperature

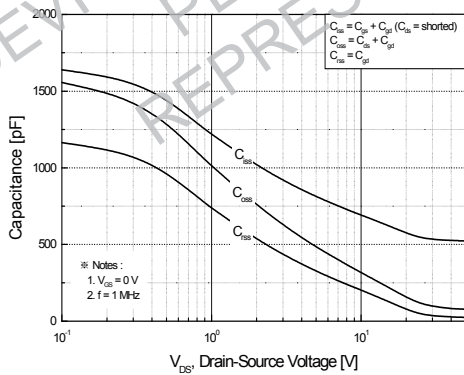


Figure 5. Capacitance Characteristics

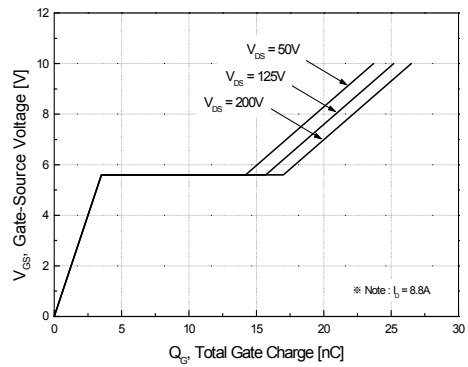


Figure 6. Gate Charge Characteristics

Typical Characteristics (Continued)

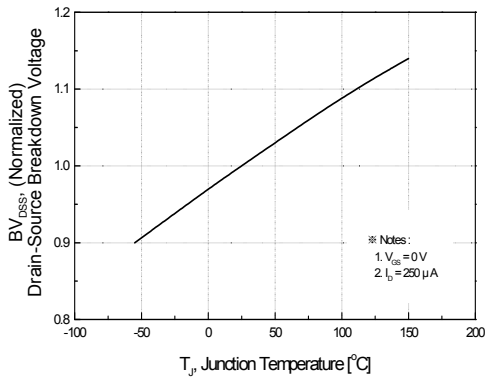


Figure 7. Breakdown Voltage Variation vs Temperature

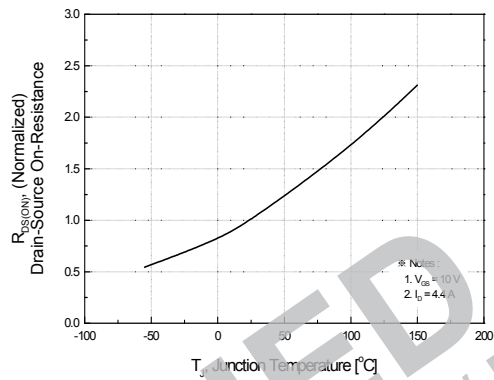


Figure 8. On-Resistance Variation vs Temperature

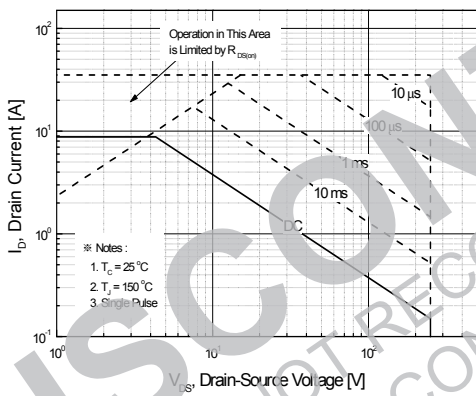


Figure 9. Maximum Safe Operating Area

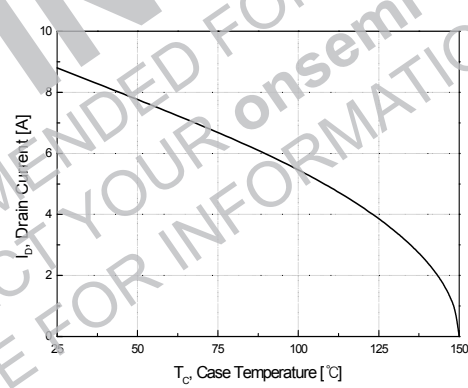


Figure 10. Maximum Drain Current vs Case Temperature

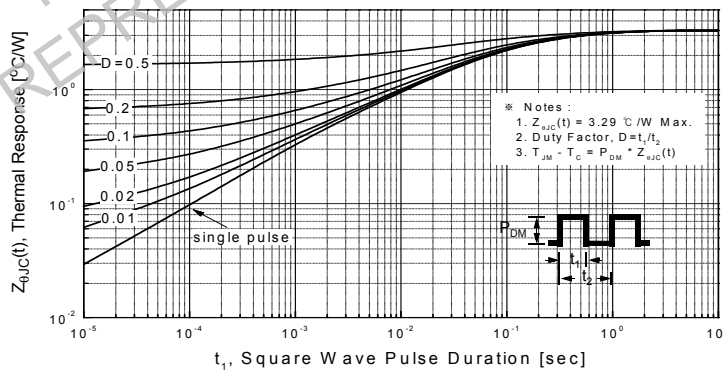


Figure 11. Transient Thermal Response Curve

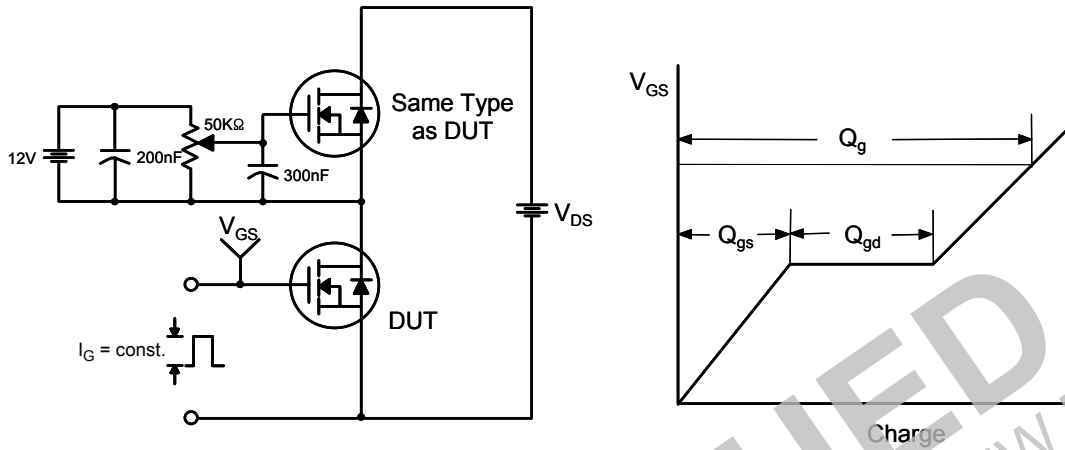


Figure 12. Gate Charge Test Circuit & Waveform

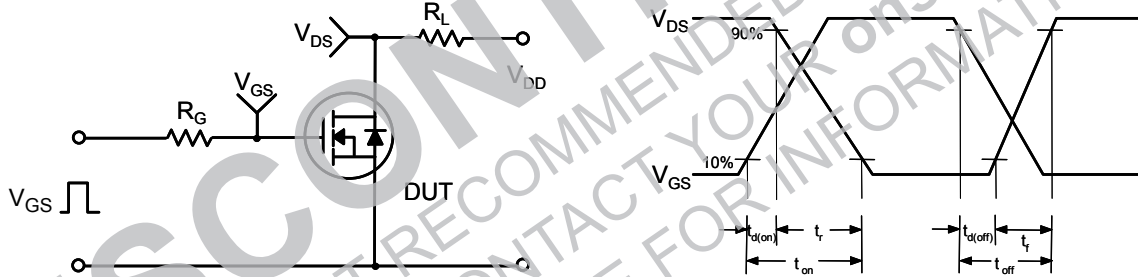


Figure 13. Resistive Switching Test Circuit & Waveforms

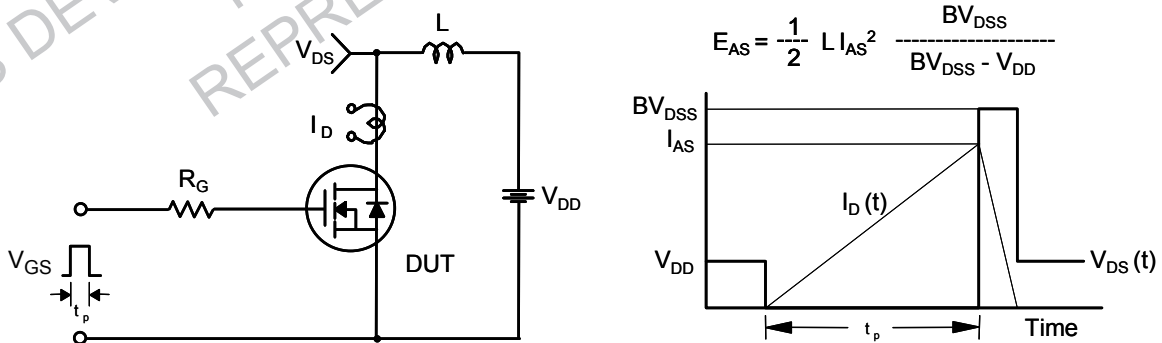


Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms

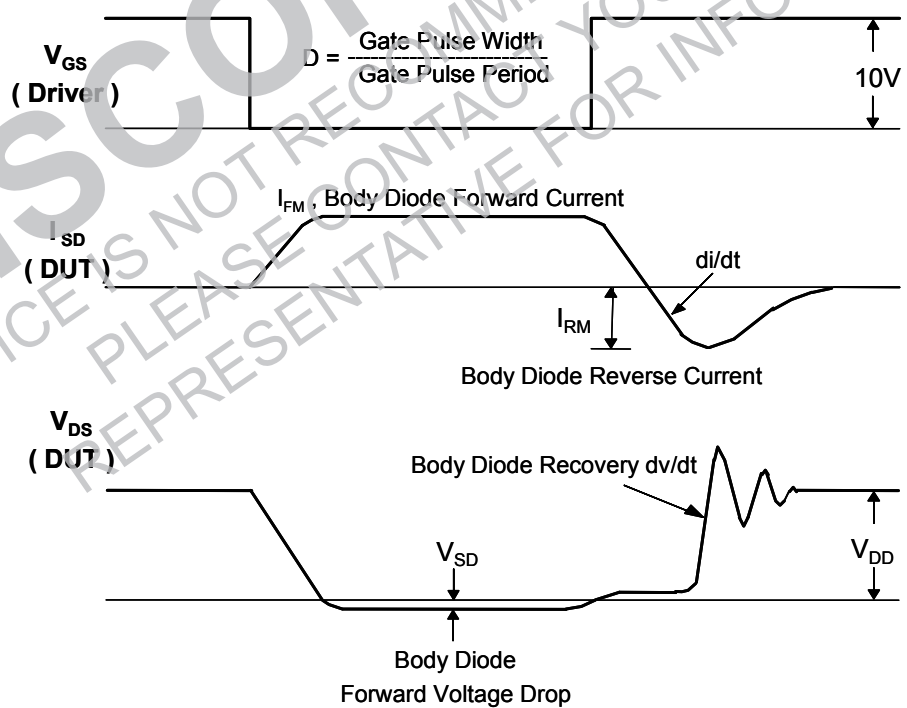
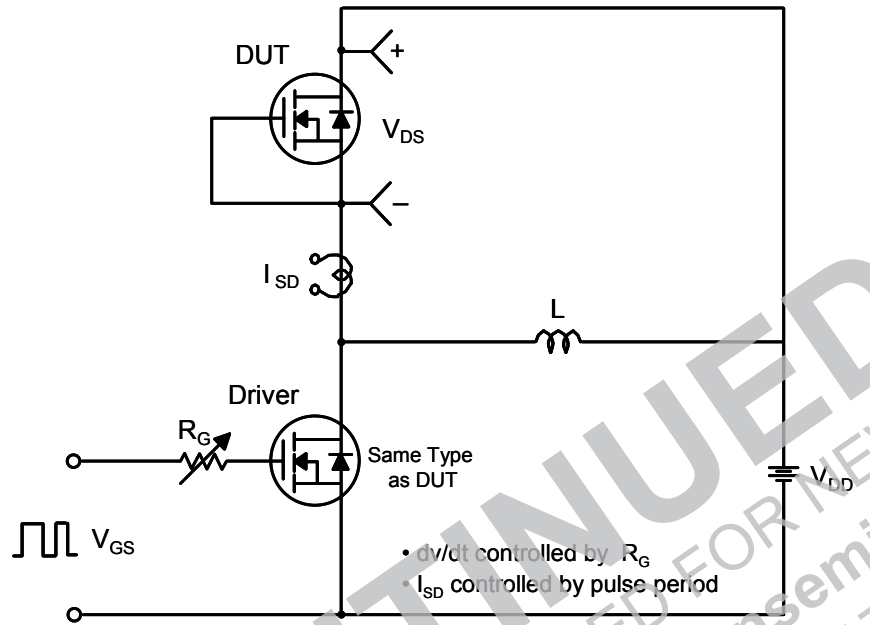
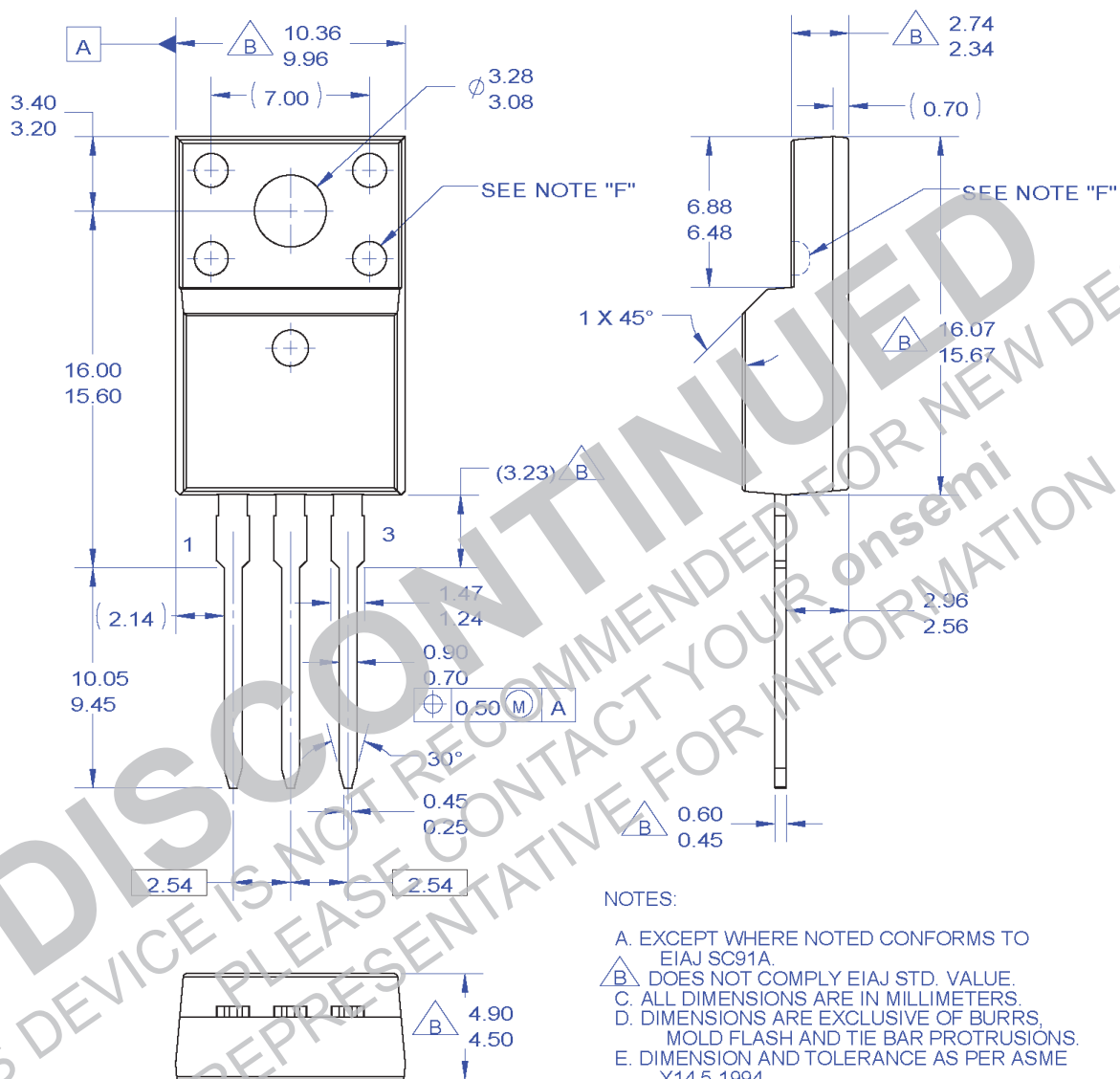


Figure 15. Peak Diode Recovery  $dv/dt$  Test Circuit & Waveforms

### Mechanical Dimensions



**Figure 16. TO220, Molded, 3-Lead, Full Pack, EIAJ SC91, Straight Lead**

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